



FORM PTO-1449/A and B (Modified)

**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

APPLICATION NO.: 09/864,817

CONFIRMATION NO.: 3443

ATTY. DOCKET NO.: C00698/70138

FILING DATE: May 24, 2001

APPLICANT: Costantino et al.

GROUP ART UNIT: 1762

EXAMINER: Rebecca A. Blanton

Sheet 1 of 2

U.S. PATENT DOCUMENTS

Examiner's Initials#	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication or of issue of Cited Document MM-DD-YY
		Number	Kind Code		
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Examiner's Initials#	Cite No.	Foreign Patent Document			Name of Patentee or Applicant of Cited Document (not necessary)	Date of Publication of Cited Document MM-DD-YYYY	Translation (Y/N)
		Office/ Country	Number	Kind Code			
RUB		JP	5058605		Mitsubishi Materials Corp	03/09/93	Y/Abstract
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RUB	*	WO	97/40199		Pathare et al.	10/30/97	

OTHER ART — NON PATENT LITERATURE DOCUMENTS

Examiner's Initials#	Cite No	Include name of the author (in CAPITAL LETTERS) title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, relevant page(s), volume-issue number(s), publisher, city and/or country where published.	Translation (Y/N)
RUB	*	Bruno et al., "Higher-Performance Multilayer Capacitor Dielectrics from Chemically Prepared Powders," May 1993.	

EXAMINER

Rebecca A. Blanton

DATE CONSIDERED

04/02

#EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

*a copy of this reference is not provided as it was previously cited by or submitted to the office in a prior application, Serial No. 08/923,680, filed September 4, 1997, and relied upon for an earlier filing date under 35 U.S.C. 120 (continuation, continuation-in-part, and divisional applications).

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